# V30DL50C-M3, V30DL50CHM3

Vishay General Semiconductor

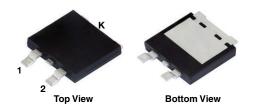
**HALOGEN** 

FREE

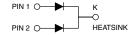
# **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.29 \text{ V}$  at  $I_F = 5 \text{ A}$ 

## TMBS® eSMP® Series TO-263AC (SMPD)



#### V30DL50C



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
$V_{RRM}$	50 V			
I <sub>FSM</sub>	300 A			
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.42 V			
T <sub>J</sub> max.	150 °C			
Package	TO-263AC (SMPD)			
Diode variations	Dual common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- AEC-Q101 qualified
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30DL50C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	50	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	30	^	
	per diode		15	- A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	300	А	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.39	-	V		
	I <sub>F</sub> = 7.5 A			0.42	-			
	I <sub>F</sub> = 15 A			0.49	0.57			
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.29	-			
	I <sub>F</sub> = 7.5 A			0.33	-			
	I <sub>F</sub> = 15 A			0.42	0.50			
Reverse current per diode	$V_R = 50 \text{ V}$ $T_A = 25 \text{ °C}$ $T_A = 125 \text{ °C}$	1 (2)	-	1800	μΑ			
		T <sub>A</sub> = 125 °C	I <sub>R</sub> <sup>(2)</sup>	25	60	mA		
Typical junction capacitance	4.0 V, 1 MHz	T <sub>A</sub> = 25 °C	CJ	2800	-	pF		

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30DL50C	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	1.7		
	per device		0.9	°C/W	
	per device	R <sub>0</sub> JA (1)(2)	45		

#### **Notes**

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AC (SMPD)	V30DL50C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel
TO-263AC (SMPD) (1)	V30DL50CHM3/I	0.55	I	2000/reel	13" diameter plastic tape and reel

#### Note

#### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

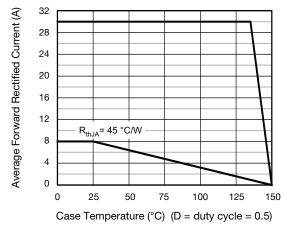


Fig. 1 - Forward Current Derating Curve

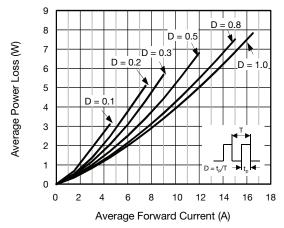
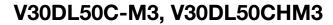


Fig. 2 - Forward Power Loss Characteristics Per Diode

<sup>(1)</sup> AEC-Q101 qualified





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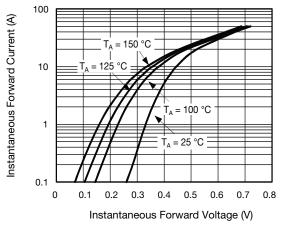


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

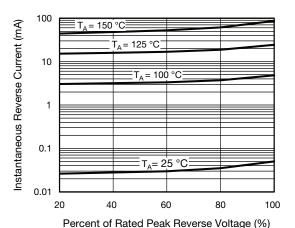


Fig. 4 - Typical Reverse Characteristics Per Diode

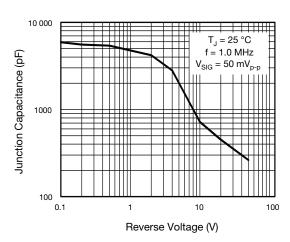


Fig. 5 - Typical Junction Capacitance Per Diode

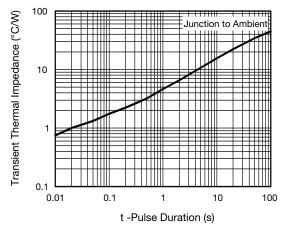


Fig. 6 - Typical Transient Thermal Impedance Per Device

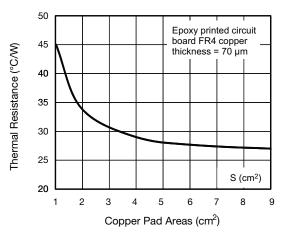
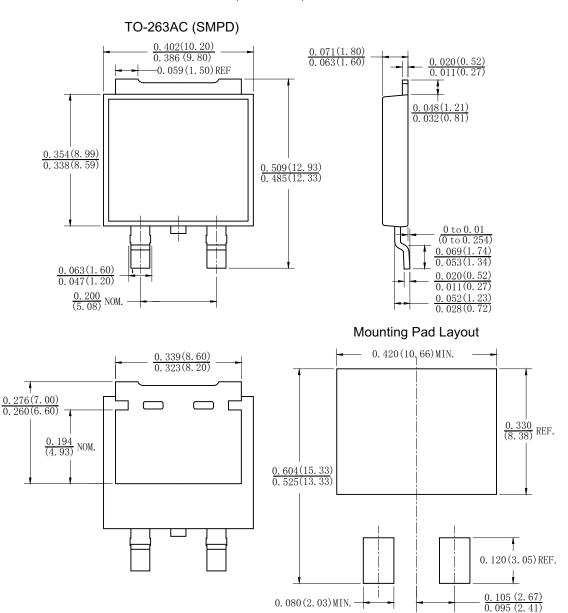


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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# AMEYA360 Components Supply Platform

# **Authorized Distribution Brand:**

























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